



DOCUMENT CHANGE REQUEST

DCR number 1183 Changes required for: General
Date: 2018/11/01 Date sent: 2018/10/15
Status: REVIEW

Originator: Aissa Nehdi
Organisation: STMicroelectronics

Title: Transistors High Power NPN, based on type 2N5154

Number: 5203/010 Issue: 7

Other documents affected:

Page:

11

Paragraph:

Paragraph : 1.7.2

Original wording:

new dimension for TO257 and SMD.5 package

Proposed wording:

new dimension for TO257 and SMD.5 package

Justification:

new dimension for TO257 and SMD.5 package

Attachments:

5203010iss7(3).pdf, 5204002iss7(3).pdf, modification_for_4_escs_specification_of_detail(3).docx, 5203016iss4(3).pdf, 5203010_draft(3).pdf

Modifications:

N/A

Approval signature:

Date signed:

2018-11-01